

HIGH-POWER NPN SILICON POWER TRANSISTORS

...designed for use in general-purpose amplifier and switching application .

FEATURES:

- * Recommend for 125W High Fiderity Audio Frequency Amplifier Output stage
- * Complementary to 2SA1302

2SC3281

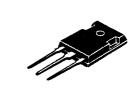
NPN

15 AMPERE POWER TRANASISTOR

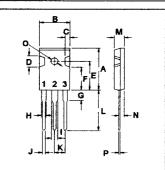
200 VOLTS 150 WATTS

MAXIMUM RATINGS

Characteristic	Symbol	2SC3281	Unit	
Collector-Emitter Voltage	V _{CEO}	200	V	
Collector-Base Voltage	V _{CBO}	200	V	
Emitter-Base Voltage	V _{EBO}	5.0	V	
Collector Current - Continuous - Peak	I _C	15 20	А	
Base current	l _B	2.0	Α	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	150 1.2	W/°C	
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150	°C	



TO-247(3P)

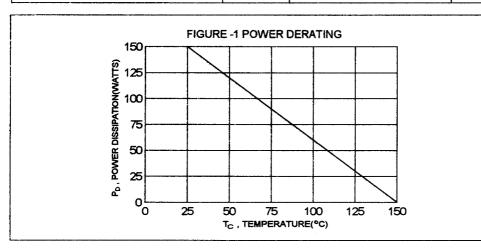


PIN 1.BASE 2.COLLECTOR 3.EMITTER

DIM	MILLIM	ETERS	
ואווע	MIN	MAX	•
Α	20.63	22.38	
В	15.38	16.20	
С	1.90	2.70	
D	5.10	6.10	
E	14.81	15.22	
F	11.72	12.84	
G	4.20	4.50	
Н	1.82	2.46	
1	2.92	3.23	
J	0.89	1.53	
K	5.26	5.66	
L	18.50	21.50	
M	4.68	5.36	
N	2.40	2.80	
0	3.25	3.65	
P	0.55	0.70	

THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
	Thermal Resistance Junction to Case	Rθjc	0.83	°C/W



Unit

Max

Characteristic

Collector-Emitter Breakdown Voltage	V _{(BR)CEO}			V
(I _C = 50 mA, I _B = 0)		200		
Collector Cutoff Current (V _{CB} = 200 V, I _E = 0)	Сво		50	uА
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)	l _{EBO}		10	uА

Symbol

Min

ON CHARACTERISTICS (1)

DC Current Gain (I _C = 1.0 A, V _{CE} = 5.0 V) * (I _C = 8.0 A , V _{CE} = 5.0 V)	hFE(2) hFE	55 35	160	
Collector-Emitter Saturation Voltage (I _C = 10 A, I _B = 1.0 A)	V _{CE(sat)}		3.0	V
Base-Emitter On Voltage (I _C = 8.0 A, V _{CE} =5.0 V)	V _{BE(on)}		1.5	V

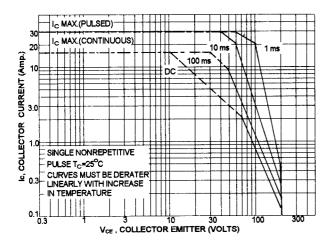
DYNAMIC CHARACTERISTICS

Current-Gain-Bandwidth Product	f_		MHz
(I _C = 1.0 A, V _{CE} = 5.0 V, f = 1.0 MHz)	• •	10	

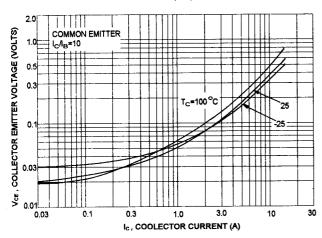
(1) Pulse Test: Pulse Width =300 us,Duty Cycle ≤ 2.0% * hFE(2) Classification :

	55	R	110	80	0	160
L				L		

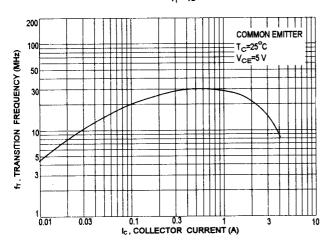
ACTIVE REGION SAFE OPERATING AREA



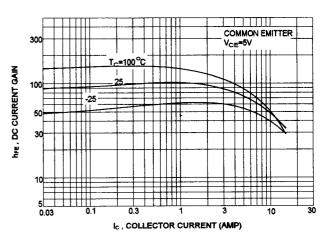
VCE(sat) - Ic



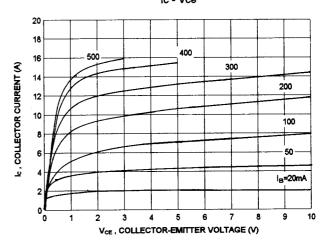
f_T - Ic



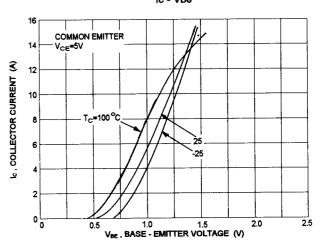
DC CURRENT GAIN



Ic - Vce



lc - Vbe



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.